



INTEGRATED CIRCUIT

TECHNICAL DATA

TA7675AP, TA7678AP

TOSHIBA BIPOLAR LINEAR INTEGRATED CIRCUIT

SILICON MONOLITHIC

VIDEO AND SOUND IF AMPLIFIER FOR COLOR AND
MONOCHROME TV RECEIVERS

TA7675AP for FET Tuner

TA7678AP for Bipolar Tuner

FUNCTION

PIF STAGE

- . Three Controlled IF Amplifier Stages
- . Video Demodulator Controlled by Picture Carrier
- . Black Noise and White Noise Inverter
- . Peak AGC
- . DC Amplifier for RF AGC Output

SIF STAGE

- . Three Controlled IF Amplifier Stages
- . Quadrature Detector

FEATURE

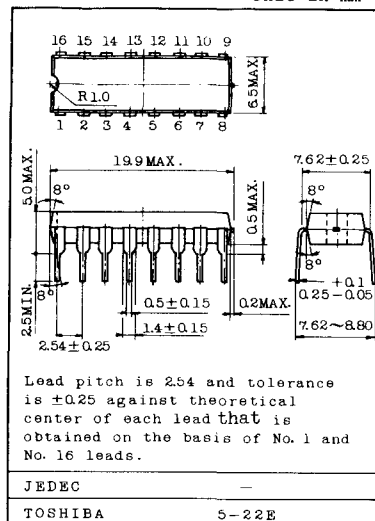
PIF STAGE

- . High Gain, Wide Band IF Amplifier : 50dB (Typ.) at 58MHz
- . Gain Reduction with Excellent Stability : 55dB (Typ.) at 58MHz
- . Excellent DG/DP Characteristics : DG 7% (Typ.), DP 3.5 deg.(Typ.)
- . Excellent S/N Characteristics Due to Delayed 3 Stage AGC Action.
- . Fast AGC Action Due to Noise Inverter and Peak AGC.
- . Switch Off the Video Part with VTR Switch.
- . Dual Differential AFT Output.

SIF STAGE

- . Excellent Limiter Characteristics.
- . Excellent AM Rejection.
- . Large Undistorted Audio Output Voltage with Quadrature Detector.

Unit in mm





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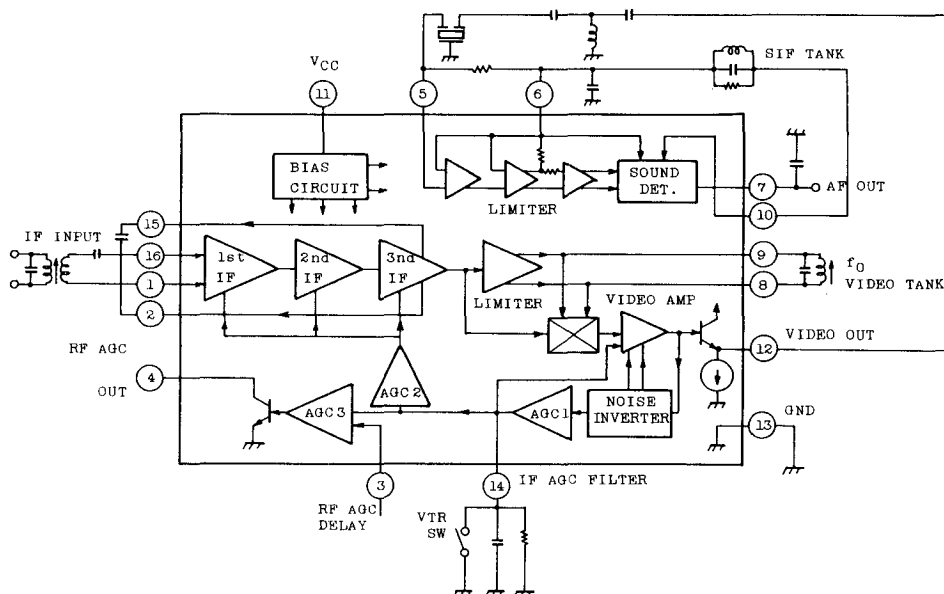
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MAXIMUM RATINGS ($T_a=25^{\circ}\text{C}$)

CHARACTERISTIC	SYMBOL	RATING	UNIT
Supply Voltage (Pin 11)	V_{CC}	15	V
Open Loop Voltage (Pin 4)	V_4	15	V
Video DC Output Current (Pin 12)	I_{12}	6	mA
Power Dissipation (Note)	P_D	1.4	W
Ambient Temperature	T_a	$-20 \sim 65$	$^{\circ}\text{C}$
Storage Temperature	T_{stg}	$-55 \sim 150$	$^{\circ}\text{C}$

Note: Derated above $T_a=25^{\circ}\text{C}$ in the proportion of $11.2\text{mW}/^{\circ}\text{C}$.

BLOCK DIAGRAM





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ELECTRICAL CHARACTERISTICS

PIF STAGE ($T_a=25^{\circ}\text{C}$, $V_{CC}=12\text{V}$, $f_p=58.75\text{MHz}$, $f_s=54.25\text{MHz}$)

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Recommended Supply Voltage	V_{CC} (V_{11})	-	-	10.8	12.0	13.2	V
Supply Current	I_{CC} (I_{11})	1	S1:ON, S3:2, S5:2 S4:1(TA7678AP) 2(TA7675AP)	35	50	65	mA
VIDEO DC Output Voltage	V_{12}	1	S1:OFF, S3:2, S5:2 S4:1(TA7678AP) 2(TA7675AP)	5.2	5.5	5.8	V
Terminal Voltage 5	V_5	1	S1:ON, S3:2, S5:2 S4:1(TA7678AP) 2(TA7675AP)	3.5	4.4	5.3	V
Terminal Voltage 7	V_7	1	S1:ON, S3:2, S5:2 S4:1(TA7678AP) 2(TA7675AP)	4.8	6.0	7.2	V
RF AGC Residual Output Voltage	V_4 SAT	1	S1:OFF, S3:2, S5:2 S4:1(TA7678AP) 2(TA7675AP)	-	-	0.5	V
RF AGC Leak Current	I_4 LEAK	1	S1:OFF, S3:1, S5:1 S4:1(TA7675AP) 2(TA7678AP)	-	-	1	μA
Video Sensitivity	v_i PIN1-16	2	(Note 1)	60	150	250	μV_{rms}
AGC Range	ΔA (IF)	2	(Note 2)	60	64	-	dB
Sync Tip Level Voltage	V_{SYNC} (V_{12})	2	(Note 3)	2.3	2.5	2.7	V
Maximum IF Input Voltage	$V_{\text{IN MAX}}$ PIF	2	(Note 4)	100	120	-	mV_{rms}
White Noise Threshold	$V_{\text{W TH}}$ (V_{12})	2	(Note 5)	5.8	6.2	6.6	V
White Noise Clamp Level	$V_{\text{W CL}}$ (V_{12})	2	(Note 5)	3.7	4.1	4.5	V
Black Noise Threshold	$V_{\text{B TH}}$ (V_{12})	2	(Note 5)	1.4	1.6	1.8	V



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PIF STAGE

CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Black Noise Clamp Level	V_B CL (V ₁₂)	2	(Note 5)	2.9	3.3	3.7	V
Video Frequency Response	f_{BW}	3	(Note 6)	4.5	5.5	—	MHz
Suppression of Carrier	CL	4	(Note 7)	40	50	—	dB
Suppression of 2nd Carrier	I _{2nd}	4	(Note 8)	40	50	—	dB
Suppression of Sound Carrier/Color Subcarrier	I ₉₂₀	4	(Note 9)	33	38	—	dB
Differential Phase	DP	5	(Note 10)	—	3.5	5	deg
Differential Gain	DG	5	(Note 10)	—	7	10	%
PIF Input Impedance	R _{IN} (PIF)	6	(Note 11)	1.5	3.0	6.0	kΩ
	C _{IN} (PIF)			—	3.0	10.0	pF
Max. Available Current	I ₄ MAX	1	(Note 12)	TA7675AP	0.3	—	mA
				TA7678AP	7.0	—	mA
RF AGC Delay Point Range	V _{IN} DELAY	2	(Note 13)	5.0	7.0	9.0	V
VIDEO Output Level	v _{OUT}	2	(Note 14)	2.25	2.5	2.75	V
SIF Output Voltage	S _{OUT}	3	(Note 15)	200	400	600	mV _{rms}

SIF STAGE

Input Limiting Voltage	V _{IN} (LIM)	8	(Note 16)	—	200	400	μV _{rms}
AM Rejection Ratio	AMR	8	(Note 17) $R_L = \infty$ $R_D = \infty$	40	45	—	dB
Recovered Output Voltage	V _{OD}	8	(Note 18) $R_L = \infty$ $R_D = \infty$	0.5	0.75	—	V _{rms}
Total Harmonic Distortion	THD	8	(Note 18) $R_L = \infty$ $R_D = \infty$	—	1.0	2.0	%
Max. Audio Output Voltage	V _O M	8	(Note 19)	4.0	—	—	V _{p-p}
SIF Input Impedance	R _{IN} (SIF)	7		10.0	20.0	30.0	kΩ
	C _{IN} (SIF)			—	3.0	10.0	pF
Audio Output Impedance	R _O (AF)	9	(Note 20)	10	15	20	kΩ



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Note 1) V_{AGC} (TP14 EXT. Applying Voltage)=11.5V

PIF IN ; $f=58.75\text{MHz}$ 1kHz 30% AM modulation.

Adjust PIF Input Level v_i so that the detected output of TP12C with high impedance probe will be $0.8V_{p-p}$ and measure the Input Level.

Note 2) $V_{AGC}=4V$

Measure PIF Input Level v_i' same as NOTE 1

$$\Delta A = 20 \log \frac{v_i'}{v_i} \quad [\text{dB}]$$

Note 3) PIF IN ; $f=58.75\text{MHz}$ CW 15mV_{rms}

Measure DC level of TP12A

Note 4) PIF IN ; $f=58.75\text{MHz}$ APL 100%, 87.5% AM modulation.

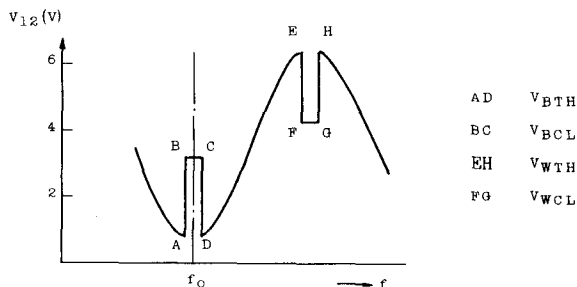
TP14:open

(1) Adjust PIF Input Level 50mV_{p-p} and measure the detected output level v_{01p-p}

(2) Then increase the Input Level so that the detected output level will be $1.1 \times v_{01p-p}$ and measure the Input Level.

Note 5) $V_{AGC}=8V$

PIF IN ; $f=58.75\text{MHz} \pm 10\text{MHz}$ Variable or Sweep 15mV_{rms} Measure DC level of TP12A.





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Note 6) $V_{AGC}=8V$ ($GR \approx 30dB$)

SG₁ : 58.75MHz CW

SG₂ : 58.65~40MHz Variable

(1) Setting output of SG₁ so that DC level of TP12A will be 4.0V

(2) Setting output of SG₂ (58.65MHz) so that AC level of TP12A will be 0.5V_{p-p}

(3) Decreasing Frequency of SG₂ until AC level of TP12A will be 0.35V_{p-p}

(-3dB of 0.5V_{p-p}) then read $f_{SG_2}=F$

$f_{BW}=58.75-F$ MHz

Note 7) SG₁ ; 58.75MHz, 1kHz 80% AM modulation 100mV_{rms}

SG₂, SG₃; OFF

Setting V_{AGC} so that output AC level of TP12A will be 2.7V_{p-p}

Measure CL of TP12A after setting to 0% AM of SG₁

Note 8) Measure I_{2nd} of TP12A same as NOTE 9

Note 9) $V_{AGC}=8V$

SG₁; 58.75MHz (P; Picture) 100mV_{rms}

SG₂; 54.25MHz (S; Sound) 32mV_{rms}(-10dB of SG₁)

SG₃; 55.17MHz (C; Chroma) 32mV_{rms}(-10dB of SG₁)

(1) Setting V_{AGC} so that the output tip level (lower) of TP12A will be 3.0V DC

(2) Measure the level difference (dB) between c-level and 920kHz level

Note 10) $V_{AGC}=8V$

PIF IN ; $f=58.75$ MHz Video Signal (ramp) 87.5% AM 100mV_{p-p}

Setting ATT so that the sync tip level of TP12A will be 2.5V DC

Measure DP and DG.

Note 11) $V_{AGC}=5V$ $f=58.75$ MHz

Measure R_{IN}, C_{IN}

Note 12) S₁:0N, S₃:2, S₅:1

S₄:1 for TA7675AP

2 for TA7678AP



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Note 13) TP14:Open

PIF IN ; 58.75MHz CW 20mV_{rms}

(1) Adjust the voltage of terminal 3 so that the voltage of terminal 4 will be 6.0V DC

(2) Measure the terminal voltage 3

Note 14) TP14:Open

PIF IN ; 58.75MHz 100% APL 87.5% AM modulation Signal Amplitude 50mV_{p-p}

Measure detected output voltage (White peak to sync Tip)

Note 15) TP14:Open

SG1 ; 58.75MHz CW 100mV_{rms}

SG2 ; 54.25MHz CW 25mV_{rms}

Measure SIF (4.5MHz) output voltage at TP12A

Note 16) SIF IN ; f=4.5MHz FM f_{MOD}=400Hz $\Delta f = \pm 25\text{kHz}$

(1) Adjust SIF Input Level 100mV_{p-p} and measure the detected output level v_{OS}

(2) Then decrease the Input Level so that the detected output level will be 3dB down of v_{OS} and measure the Input Level

Note 17) SIF IN ; f=4.5MHz FM : f_{MOD}=400Hz $\Delta f = \pm 25\text{kHz}$

AM 30%

Input Level $v_{INs} = 100\text{dB}\mu$

Note 18) SIF IN ; f=4.5MHz FM : f_{MOD}=400Hz $\Delta f = \pm 25\text{kHz}$

Input Level $v_{INs} = 80\text{dB}\mu$

Note 19) SIF IN ; f=4.4~4.6MHz Variable or Sweep

Measure the output DC voltage change

Note 20) SIF IN ; f=4.5MHz FM : f_{MOD}=400Hz $\Delta f = \pm 25\text{kHz}$

Input Level $v_{INs} = 80\text{dB}\mu$

(1) Measure the detected output voltage v_{OA} with $R_X = \infty$

(2) Then, adjust R_X so that the detected output voltage will be $\frac{v_{OA}}{2}$ and measure R_X .

Fig. 1 DC TEST CIRCUIT

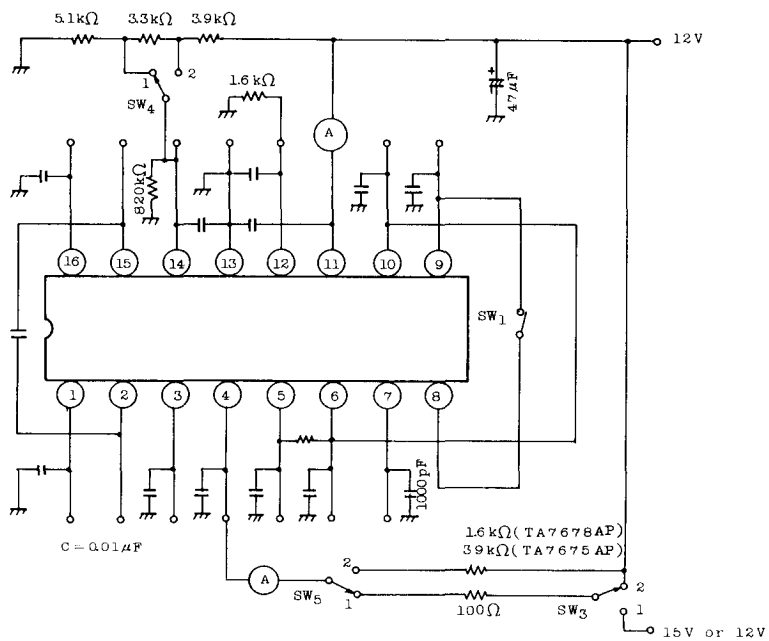
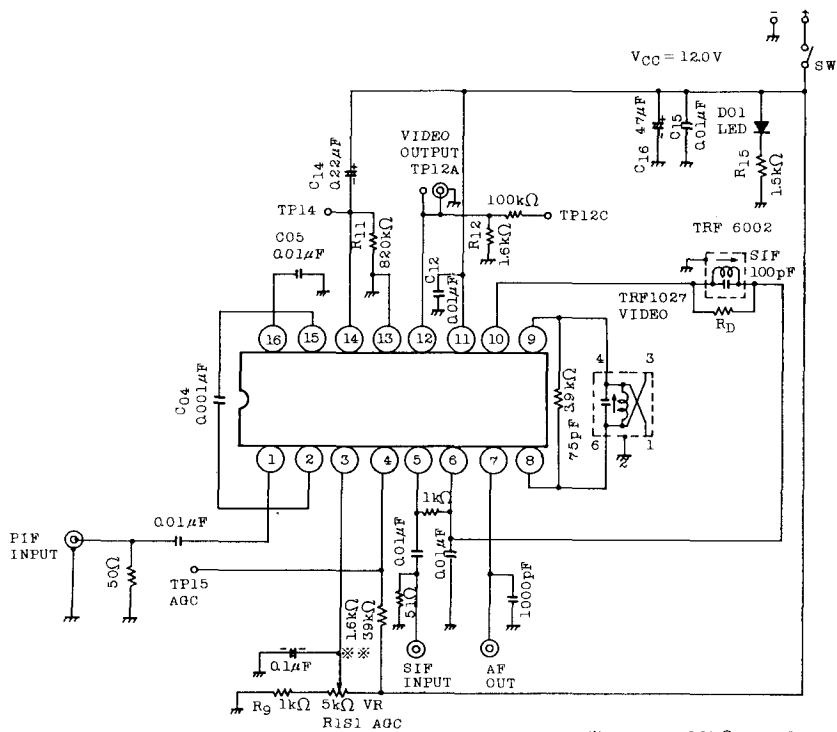


Fig. 2 AC TEST CIRCUIT



※ Note 39kΩ : TA7675AP
 1.6kΩ : TA7678AP

Fig. 3 Video Frequency Response & SIF Output Voltage TEST CIRCUIT

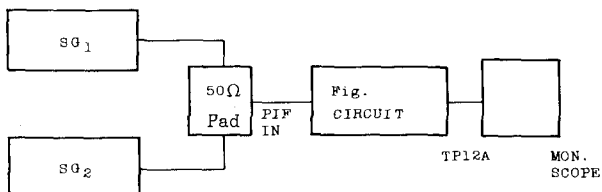


Fig. 4 Inter Modulation TEST CIRCUIT

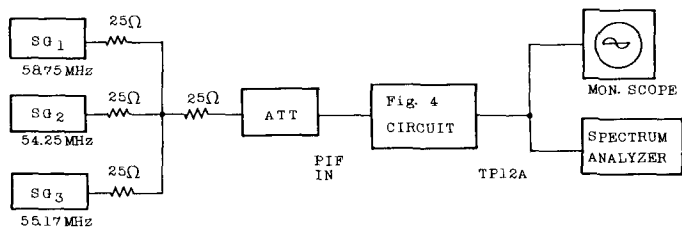
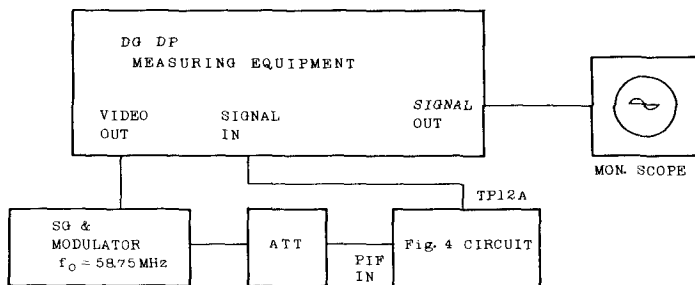


Fig. 5 DG, DP TEST CIRCUIT



APL = 50%

ATT : ADJUST SYNC TIP LEVEL to DC2.5V

Fig. 6 PIF Input Impedance TEST CIRCUIT

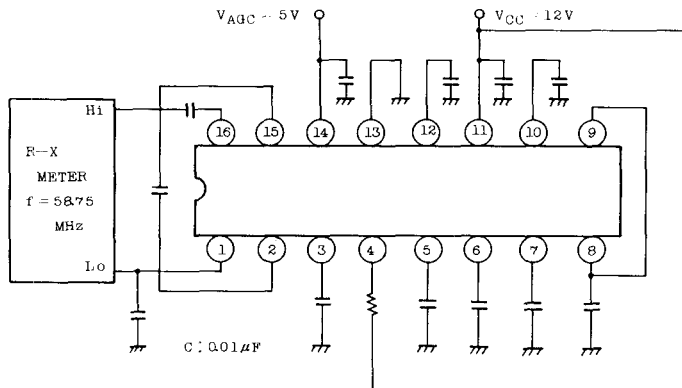
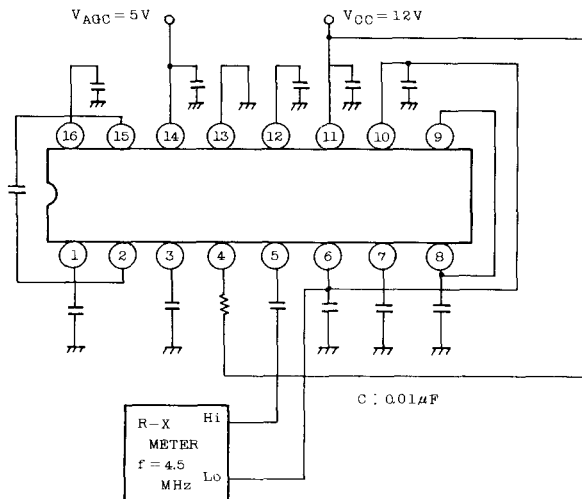


Fig. 7 SIF Input Impedance TEST CIRCUIT





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Fig. 8 $v_{IN(LIM)}$, AMR, V_{OD} , THD, V_{OM} TEST CIRCUIT

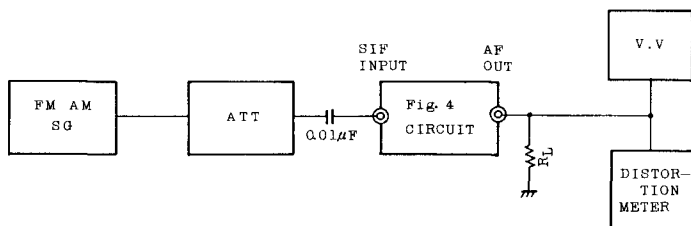
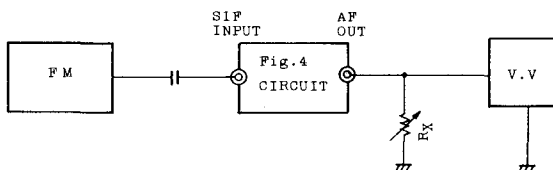


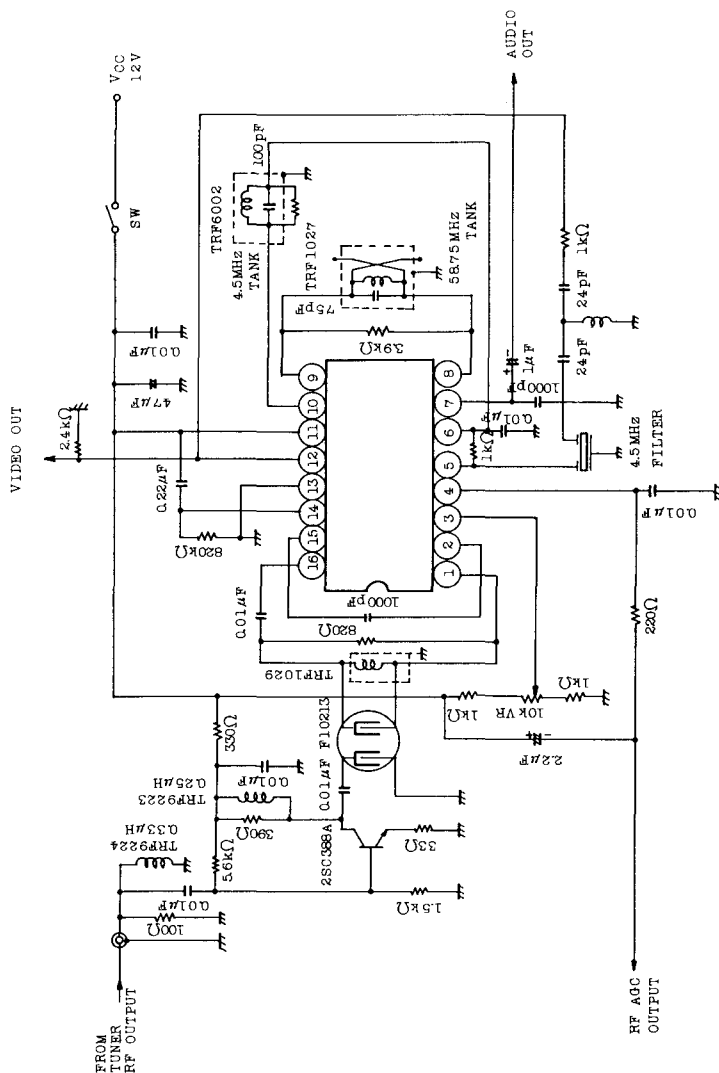
Fig. 9 Audio Output Impedance TEST CIRCUIT





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TA7675AP, TA7678AP APPLICATION CIRCUIT